VANGUARD ELECTRONICS



COTS +

# CMN30 SERIES NANOCRYSTALLINE COMMON MODE CHOKE



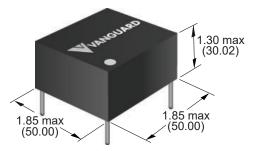
- **ELECTRICAL SPECIFICATIONS**
- Operating Temperature: -55°C to +125°C
- Storage Temperature: -60°C to +130°C
- Temperature Rise @ 100°C: < 30°C
- Dielectric Withstanding Voltage: 1000 V<sub>RMS</sub>
- Overload Current: 1.5 times rated current
- Different electrical values available upon request

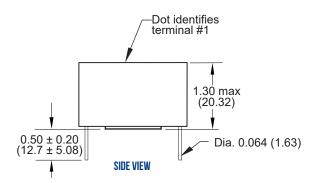
### FEATURES

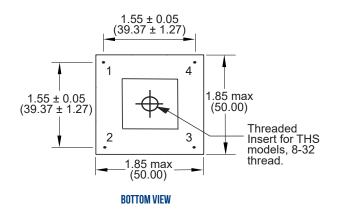
- Terminations: SnPb, Lead Free (RoHS)
- Insert: Threaded insert can be added to component.
- Resistance to Soldering Heat: 265°C for 10 seconds
- Moisture, Shock and Immersion Resistant
- Magnetically Shielded
- Ideally designed for GaN applications and higher switching frequencies
- Designed with nanocrystalline core for superior thermal stability and higher frequency operations



MARKINGS: LASER ETCH OR INK







#### CUSTOM DESIGNS & MODIFICATIONS:

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**SCHEMATIC** 

Other electrical configurations and performance characteristics are available in various sizes and package types



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O 3

REV D

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## **DATA TABLE**

Vanguard P/N	Inductance @ 10kHz ± 30% (mH)	DCR Max (Ohms)	Rated Current (A)	
CMN30-903TH	0.9	0.0022	22.5	
CMN30-274TH	2.7	0.004	16.9	
CMN30-554TH	5.5	0.006	14.2	
CMN30-804TH	8.0	0.008	11.6	
CMN30-125TH	12.5	0.011	9.9	
CMN30-255TH	25.0	0.028	6.2	
CMN30-505TH	50.0	0.064	4.2	
CMN30-755TH	75.0	0.100	3.3	
CMN30-106TH	100	0.145	2.8	
CMN30-156TH	150	0.280	2.0	
CMN30-206TH	200	0.510	1.5	

1/ Inductance measured at 10 kHz, 0.10 VRMS

 $\underline{2}$ / DCR measured at room ambient temperature (25°C)

#### VE PART NUMBER STRUCTURE KEY INDUCTANCE

## (uH) (mH)

903 = 900 uH 274 = 2.7 mH 206 = 200 mH

TERMINATION	

EXAMPLE: CMN30-903THS-1-B

### RELIABILITY

#### PACKAGING (Default Bulk)

				_		
S	SnPb	1	COTS/EM		В	Bulk
R	Pure Tin	7	Other			

#### **CUSTOM DESIGNS & MODIFICATIONS:**

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